NSN 5961-01-167-8566

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-167-8566 **Inclosure Material:** Metal **Overall Length:** 9.670 inches **Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.250 inches **Criticality Code Justification:** Feat Voltage Rating In Volts Per Characteristic: 1000.0 repetitive peak off-state voltage and 1000.0 repetitive peak reverse voltage and 1100.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 235.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 16.00 watts small-signal input power, common-collector blank and 3.0 watts small-signal input power, common-collector universal **Special Features:** Item must comply with requirements of defense supply center columbus production standard no. Lo3322 **Reference Number Differentiating Characteristics:** Areference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: